

## EAST Search History

## EAST Search History (Prior Art)

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L1	491	nano adj rod	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/07/13 16:18
L2	2543	nanorod	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/07/13 16:18
L3	2954	1 or 2	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/07/13 16:18
L4	705	metal near10 3	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/07/13 16:18
L5	358	3 near5 ((zinc adj oxide) or "ZnO" or (titanium adj oxide) or "TiO" or GaN or Si or InP or InAs or GaAs)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/07/13 16:20
L6	40	4 same (metal near3 (Ni or Pt or Pd or Au or W or PtSi or NiSi))	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/07/13 16:21
L7	94	4 same3 (metal near5 (Ni or Pt or Pd or Au or W or PtSi or NiSi))	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/07/13 16:31

L8	54	7 not 6	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/07/13 16:32
L9	8	5 near10 (ohmic adj2 contact)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/07/13 16:34
L10	14	5 same (ohmic adj2 contact)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/07/13 16:35
L11	6	10 not 9	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/07/13 16:35
L12	20	5 same3 ((ohmic adj2 contact) or schottky)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/07/13 16:36
L13	6	12 not 10	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/07/13 16:36
L14	178	3 near2 semiconductor	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/07/13 16:38
L15	11	14 same2 ((ohmic adj2 contact) or schottky)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/07/13 16:38

L16	0	14 same2 (metallization)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/07/13 16:39
L17	11	14 same4 (ohmic or schottky)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/07/13 16:39
L18	9	17 not 10	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/07/13 16:39
L19	2466	nano near5 ((zinc adj oxide) or "ZnO" or (titanium adj oxide) or "TiO" or GaN or Si or InP or InAs or GaAs)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/07/13 16:43
L20	23	19 same (ohmic or schottky)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/07/13 16:43
L21	19	20 not 10	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/07/13 16:43
L22	63	3 same (ohmic or schottky)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/07/13 16:45
L23	51	22 not 20	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/07/13 16:45

L24	1371	nano adj wire	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/07/13 17:01
L25	7581	nanowire	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/07/13 17:01
L26	8579	24 or 25	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/07/13 17:01
L27	274	26 same (ohmic or schottky)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/07/13 17:02
L28	240	26 same ((ohmic adj2 contact) or schottky)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/07/13 17:02
L29	1249	26 near5 ((zinc adj oxide) or "ZnO" or (titanium adj oxide) or "TiO" or GaN or Si or InP or InAs or GaAs)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/07/13 17:02
L30	39	29 same ((ohmic adj2 contact) or schottky)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/07/13 17:03
L31	233	29 near5 semiconductor	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/07/13 17:04

L32	6	31 same (ohmic or schottky)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/07/13 17:05
L33	7414	contact adj2 fabric	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/07/13 17:07
L34	2954	3 same 3	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/07/13 17:07
L35	63	34 same (ohmic or schottky)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/07/13 17:07
S1	2017	nanorod	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/11/13 16:04
S2	228	S1 same contact	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/11/13 16:04
S3	88	S2 same metal	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/11/13 16:04
S4	37	S3 same3 semiconductor	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/11/13 16:04

S5	14	ohmic same4 S3	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/11/13 16:05
S6	19	schottky same4 S3	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/11/13 16:05
S7	4	S5 and S6	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/11/13 16:05
S8	12	(Ni or Pt or Pd or Au or W or PtSi or NiSi) same4 S4	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/11/13 16:11
S9	828	S1 same metal	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/11/13 16:19
S10	302	S9 same semiconductor	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/11/13 16:19
S11	170	S1 near3 ((zinc adj oxide) or (titanium adj oxide) or GaN or Si InP or GaAs)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/11/13 16:21
S12	19	S11 same contact	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/11/13 16:21
S13	1	("5505928").PN.	US-PGPUB; USPAT; USOCR	OR	OFF	2008/11/13 18:04

S14	358	nanorod near3 (metallized or metal or metallic)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/11/13 18:10
S15	89	(Ni or Pt or Pd or Au or W or PtSi or NiSi) same4 S14	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/11/13 18:10
S16	8	nanorod near3 (metallized)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/11/13 18:12
S17	0	("2005/0167646").URPN.	USPAT	OR	ON	2008/11/13 18:12
S18	0	("2005/0167646").URPN.	USPAT	OR	ON	2008/11/13 18:12
S19	0	("2005/0167646").URPN.	USPAT	OR	ON	2008/11/13 18:12
S20	8	nanorod near3 ((metal or metallic) near2 contact)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/11/13 18:13
S21	11	nanorod near15 ((metal or metallic) near2 contact)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/11/13 18:13
S22	67428	rod near3 (metallized or metal or metallic)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/11/13 18:17
S23	224	rod near3 (metallized)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/11/13 18:17

S24	0	S23 same nanometer	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/11/13 18:18
S25	1	S23 same nano	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/11/13 18:18
S26	2206	rod near3 ((metal or metallic) near3 (contact or tip))	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/11/13 18:19
S27	2	nano same S26	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/11/13 18:19
S28	15151	semiconductor near3 (island or column)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/11/13 18:26
S29	2143	diameter near3 (nano)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/11/13 18:27
S30	1	S28 near10 S29	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/11/13 18:27
S31	4	S28 same S29	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/11/13 18:27



S32	3	S31 not S30	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/11/13 18:27
S33	1580	nano near3 (wire)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/11/13 18:28
S34	1	S33 near3 (metallized)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/11/13 18:28
S35	9958	semiconductor near3 polymer	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/11/13 18:31
S36	6812	semiconductor near2 polymer	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/11/13 18:31
S37	3316	semiconductor near polymer	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/11/13 18:31
S38	5	S33 same (metallized)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/11/13 18:33
S39	4	S38 not S34	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/11/13 18:33

S40	1	(Ni or Pt or Pd or Au or W or PtSi or NiSi) and S34	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/11/13 18:33
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